



# **Product Summary**

BV <sub>DSS</sub>	Rds(on)	Package	Ι <sub>D</sub> T <sub>A</sub> = +25°C	
600V	$100\Omega @ V_{GS} = 10V$	SOT23	80mA	

## Description

This new generation uses advanced planar technology MOSFET, provide excellent high voltage and fast switching, making it ideal for small-signal and level shift applications.

# **Applications**

- Motor Control
- Backlighting
- DC-DC Converters
- Power Management Functions



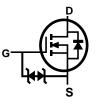
#### N-CHANNEL ENHANCEMENT MODE FIELD MOSFET

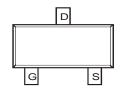
#### Features

- Low Input Capacitance
- High BV<sub>DSS</sub> Rating for Power Application
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

# **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)





ESD PROTECTED

Top View

#### Ordering Information (Note 4)

Part Number	Case	Packaging		
DMN60H080DS-7	SOT23	3000/Tape & Reel		
DMN60H080DS-13	SOT23	10000/Tape & Reel		

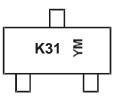
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



K31 = Product Type Marking Code YM or  $\overline{Y}$ M= Date Code Marking Y or  $\overline{Y}$  = Year (ex: E = 2017) M = Month (ex: 9 = September)

Date Code Key

Dale Code Rey												
Year	2017		2018	2019	)	2020	2021		2022	2023		2024
Code	E		F	G		Н	l		J	K		L
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	600	V		
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 5) V <sub>GS</sub> = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	70 56	mA
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	80 70	mA
Continuous Drain Current (Note 5) $V_{GS}$ = 4.5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	40 32	mA
Continuous Drain Current (Note 6) $V_{GS}$ = 4.5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	50 40	mA
Pulsed Drain Current @ T <sub>SP</sub> = +25°C (Note 7)	I <sub>DM</sub>	0.2	А		

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation, $@T_A = +25^{\circ}C$ (Note 5)	PD	0.70	W
Thermal Resistance, Junction to Ambient @ $T_A = +25^{\circ}C$ (Note 5)	R <sub>θJA</sub>	174	°C/W
Power Dissipation, @T <sub>A</sub> = +25°C (Note 6)	PD	1.10	W
Thermal Resistance, Junction to Ambient @ $T_A = +25^{\circ}C$ (Note 6)	R <sub>0JA</sub>	99	°C/W
Operating and Storage Temperature Range	TJ, T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)			, , , , , , , , , , , , , , , , , , ,			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	600	—		V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>	_	_	1	μA	$V_{DS} = 600V, V_{GS} = 0V$
Gate-Body Leakage	I <sub>GSS</sub>	_	_	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage		1.5	_	3.0	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
Gale Theshold Vollage	V <sub>GS(TH)</sub>	1.5	—	2.6	V	$V_{DS} = V_{GS}, I_D = 8\mu A$
Static Drain-Source On-Resistance	Р	-	67	100	Ω	$V_{GS} = 10V, I_D = 60mA$
Static Diam-Source Off-Resistance	R <sub>DS(ON)</sub>	-	95	290	12	$V_{GS} = 4.5V, I_D = 60mA$
Forward Transfer Admittance	Y <sub>fs</sub>	-	76	—	ms	$V_{DS} = 10V, I_D = 60mA$
Diode Forward Voltage	V <sub>SD</sub>	-	—	1.5	V	$V_{GS} = 0V, I_{S} = 50mA$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C <sub>iss</sub>		25	_		V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1.0MHz
Output Capacitance	Coss	_	5.2	_	pF	
Reverse Transfer Capacitance	Crss	-	1.4	—		
Total Gate Charge	Qg	_	1.7	_		
Gate-Source Charge	Q <sub>gs</sub>	_	0.3	_	nC	$V_{GS} = 10V, V_{DD} = 300V,$ $I_{D} = 0.01A$
Gate-Drain Charge	Q <sub>gd</sub>	_	0.9	_		ID = 0.01A
Turn-On Delay Time	t <sub>D(ON)</sub>	_	7	_	ns	
Turn-On Rise Time	t <sub>R</sub>	_	10	_	ns	$V_{DD} = 300V, V_{GS} = 10V,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	21		ns	- R <sub>GEN</sub> = 3.3Ω, - I <sub>D</sub> = 60mA
Turn-Off Fall Time	tF	_	158	_	ns	
Reverse Recovery Time	t <sub>RR</sub>	_	189.1	_	ns	V <sub>R</sub> =300V, I <sub>F</sub> =0.06A,
Reverse Recovery Charge	Q <sub>RR</sub>		32		nC	di/dt = 100A/µs

Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
Repetitive rating, pulse width limited by junction temperature, 10µs pulse, duty cycle = 1%.

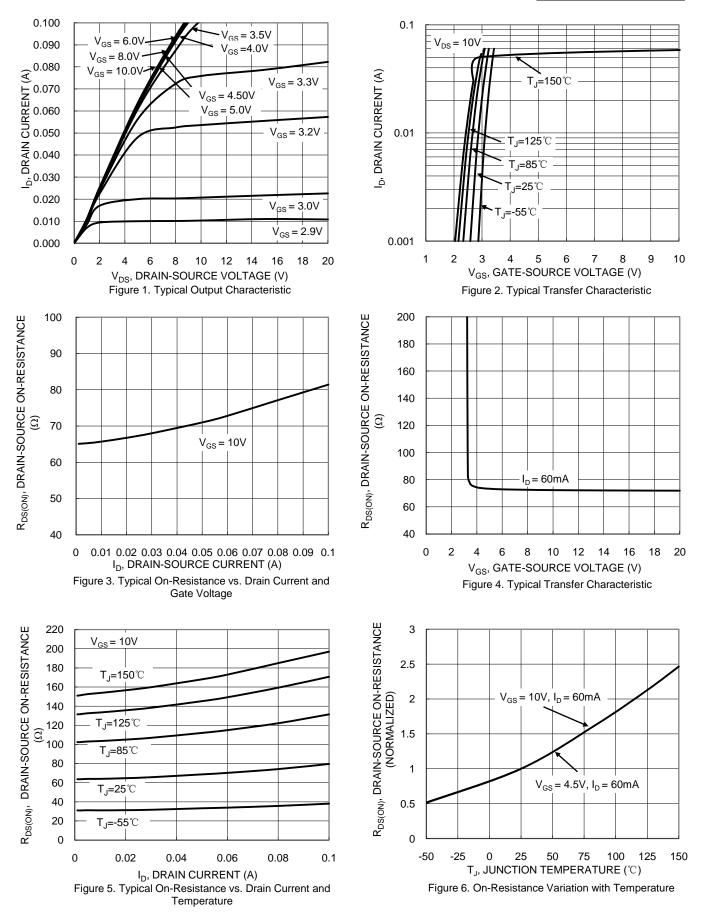
8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to production testing.

Notes:

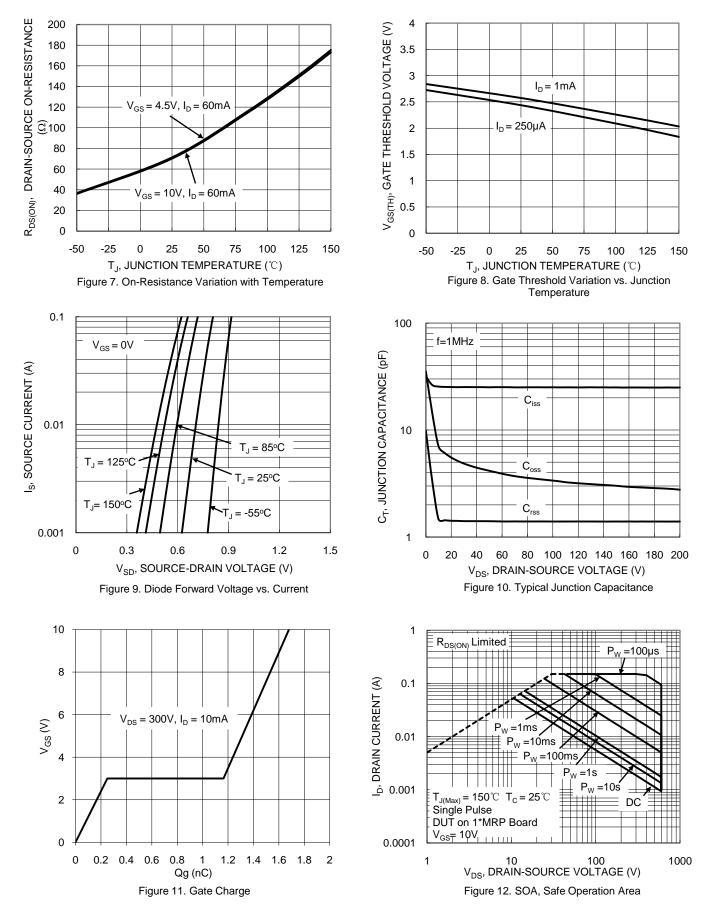


# DMN60H080DS

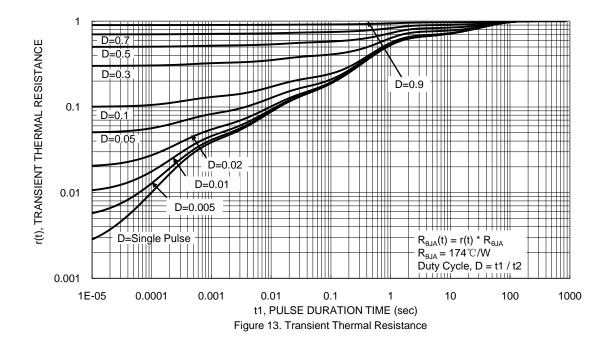




# DMN60H080DS







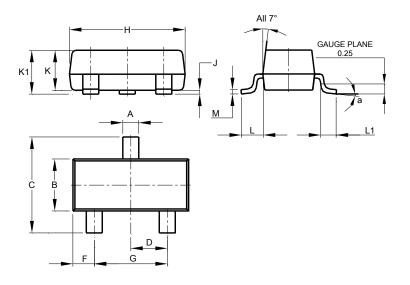


# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

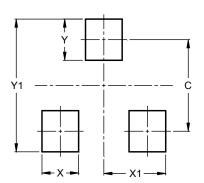
SOT23



SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
Κ	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
Μ	0.085	0.150	0.110			
а	0°	8°				
All Dimensions in mm						

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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